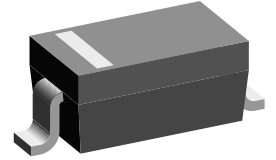


## Small Signal Zener Diodes

### Features

- Silicon planar Zener diodes
- Standard Zener voltage tolerance is  $\pm 5\%$ .
- High temperature soldering guaranteed:  
260 °C/4x10 s set terminals
- These diodes are also available in DO35 case with the type designation 1N4681...1N4717 and SOT23 case with the type designation MMBZ4681-V... MMBZ4717-V
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



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### Mechanical Data

**Case:** SOD123 plastic case

**Weight:** approx. 9.3 mg

#### Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box

GS08/3K per 7" reel (8 mm tape), 15K/box

### Absolute Maximum Ratings

$T_{amb} = 25\text{ °C}$ , unless otherwise specified

Parameter	Test conditions	Symbol	Value	Unit
Zener current (see Table "Characteristics")				
Power dissipation	$T_L = 75\text{ °C}$	$P_{tot}$	500 <sup>1)</sup>	mW

#### Note

<sup>1)</sup> On FR - 4 or FR - 5 board with minimum recommended solder pad layout

### Thermal Characteristics

$T_{amb} = 25\text{ °C}$ , unless otherwise specified

Parameter	Test conditions	Symbol	Value	Unit
Thermal resistance junction to ambient air		$R_{thJA}$	340 <sup>1)</sup>	K/W
Maximum junction temperature		$T_j$	150	°C
Storage temperature range		$T_{stg}$	- 55 to + 150	°C

#### Note

<sup>1)</sup> On FR - 4 or FR - 5 board with minimum recommended solder pad layout

# MMSZ4681-V to MMSZ4717-V



Vishay Semiconductors

## Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Maximum  $V_F = 0.9\text{ V}$  at  $I_F = 10\text{ mA}$

Partnumber	Marking code	Zener voltage <sup>1)</sup>			Max. reverse current	Test voltage
		$V_Z$ at $I_{ZT} = 50\text{ }\mu\text{A}$				
		V			$\mu\text{A}$	V
		typ.	min.	max.		
MMSZ4681-V	CF	2.4	2.28	2.52	2	1
MMSZ4682-V	CH	2.7	2.57	2.84	1	1
MMSZ4683-V	CJ	3	2.85	3.15	0.8	1
MMSZ4684-V	CK	3.3	3.14	3.47	7.5	1.5
MMSZ4685-V	CM	3.6	3.42	3.78	7.5	2
MMSZ4686-V	CN	3.9	3.71	4.1	5	2
MMSZ4687-V	CP	4.3	4.09	4.52	4	2
MMSZ4688-V	CT	4.7	4.47	4.94	10	3
MMSZ4689-V	CU	5.1	4.85	5.36	10	3
MMSZ4690-V	CV	5.6	5.32	5.88	10	4
MMSZ4691-V	CA	6.2	5.89	6.51	10	5
MMSZ4692-V	CX	6.8	6.46	7.14	10	5.1
MMSZ4693-V	CY	7.5	7.13	7.88	10	5.7
MMSZ4694-V	CZ	8.2	7.79	8.61	1	6.2
MMSZ4695-V	DC	8.7	8.27	9.14	1	6.6
MMSZ4696-V	DD	9.1	8.65	9.56	1	6.9
MMSZ4697-V	DE	10	9.5	10.5	1	7.6
MMSZ4698-V	DF	11	10.5	11.6	0.05	8.4
MMSZ4699-V	DH	12	11.4	12.6	0.05	9.1
MMSZ4700-V	DJ	13	12.4	13.7	0.05	9.8
MMSZ4701-V	DK	14	13.3	14.7	0.05	10.6
MMSZ4702-V	DM	15	14.3	15.8	0.05	11.4
MMSZ4703-V	DN	16	15.2	16.8	0.05	12.1
MMSZ4704-V	DP	17	16.2	17.9	0.05	12.9
MMSZ4705-V	DT	18	17.1	18.9	0.05	13.6
MMSZ4706-V	DU	19	18.1	20	0.05	14.4
MMSZ4707-V	DV	20	19	21	0.01	15.2
MMSZ4708-V	DA	22	20.9	23.1	0.01	16.7
MMSZ4709-V	DZ	24	22.8	25.2	0.01	18.2
MMSZ4710-V	DY	25	23.8	26.3	0.01	19
MMSZ4711-V	EA	27	25.7	28.4	0.01	20.4
MMSZ4712-V	EC	28	26.6	29.4	0.01	21.2
MMSZ4713-V	ED	30	28.5	31.5	0.01	22.8
MMSZ4714-V	EE	33	31.4	34.7	0.01	25
MMSZ4715-V	EF	36	34.2	37.8	0.01	27.3
MMSZ4716-V	EH	39	37.1	41	0.01	29.6
MMSZ4717-V	EJ	43	40.9	45.2	0.01	32.6

**Note**

<sup>1)</sup> Measured with device junction in thermal equilibrium

## Typical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

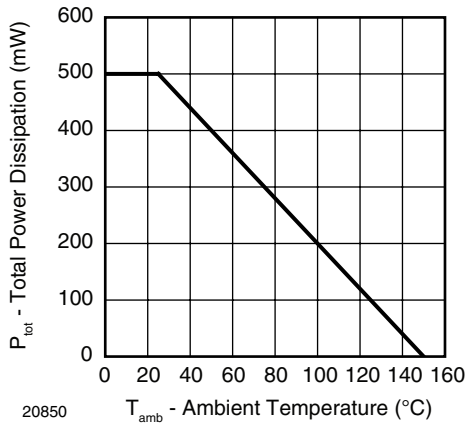


Figure 1. Total Power Dissipation vs. Ambient Temperature

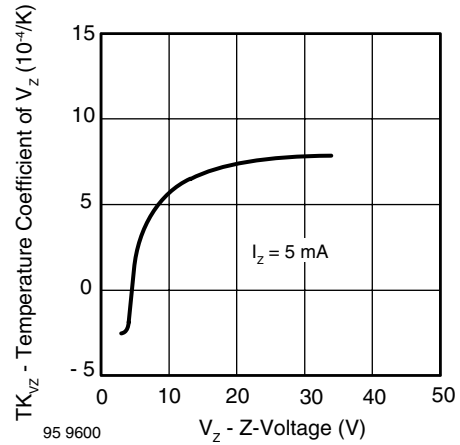


Figure 4. Temperature Coefficient of Vz vs. Z-Voltage

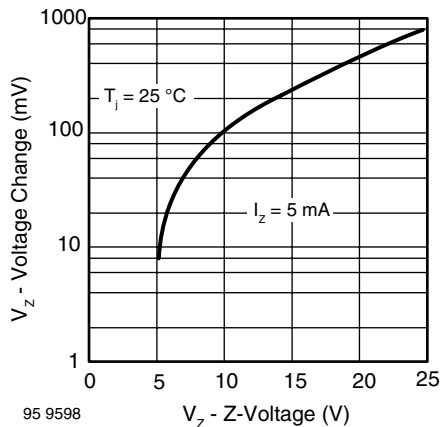


Figure 2. Typical Change of Working Voltage under Operating Conditions at  $T_{amb}=25\text{ }^{\circ}\text{C}$

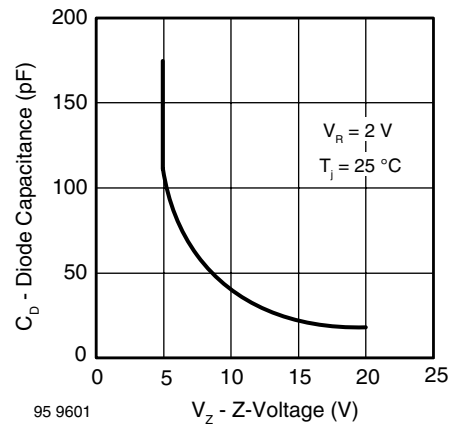


Figure 5. Diode Capacitance vs. Z-Voltage

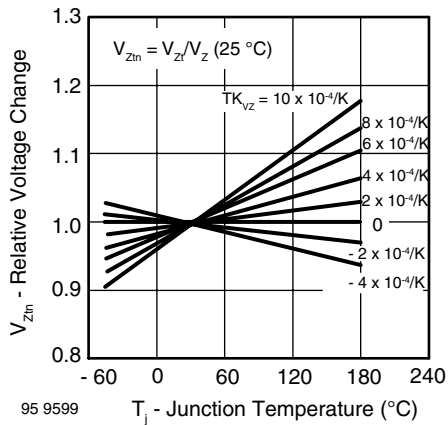


Figure 3. Typical Change of Working Voltage vs. Junction Temperature

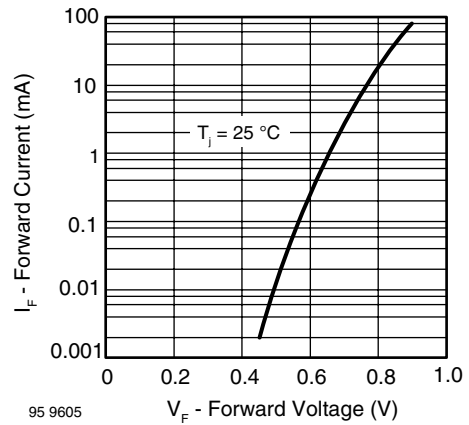


Figure 6. Forward Current vs. Forward Voltage

# MMSZ4681-V to MMSZ4717-V



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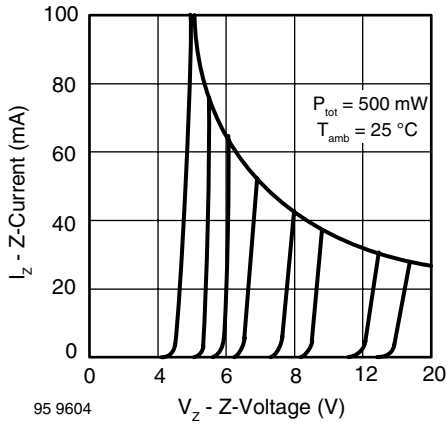


Figure 7. Z-Current vs. Z-Voltage

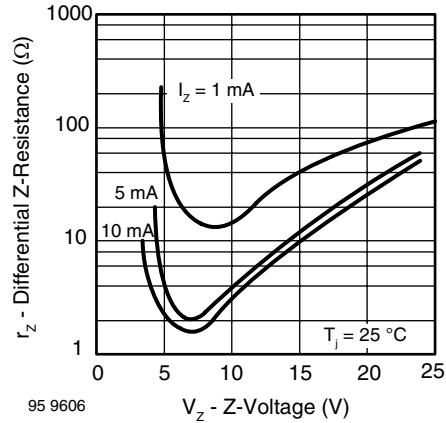


Figure 9. Differential Z-Resistance vs. Z-Voltage

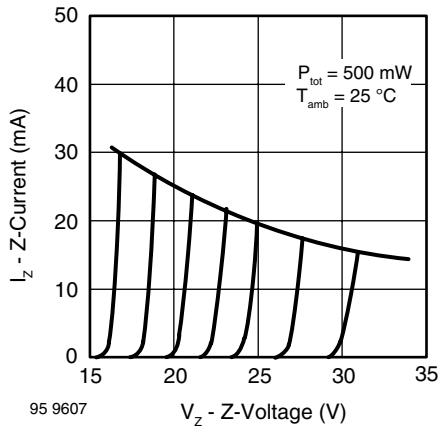


Figure 8. Z-Current vs. Z-Voltage

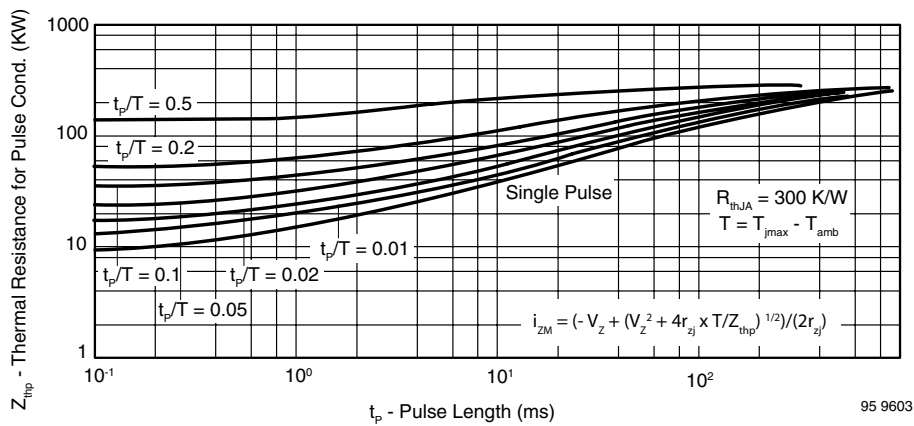


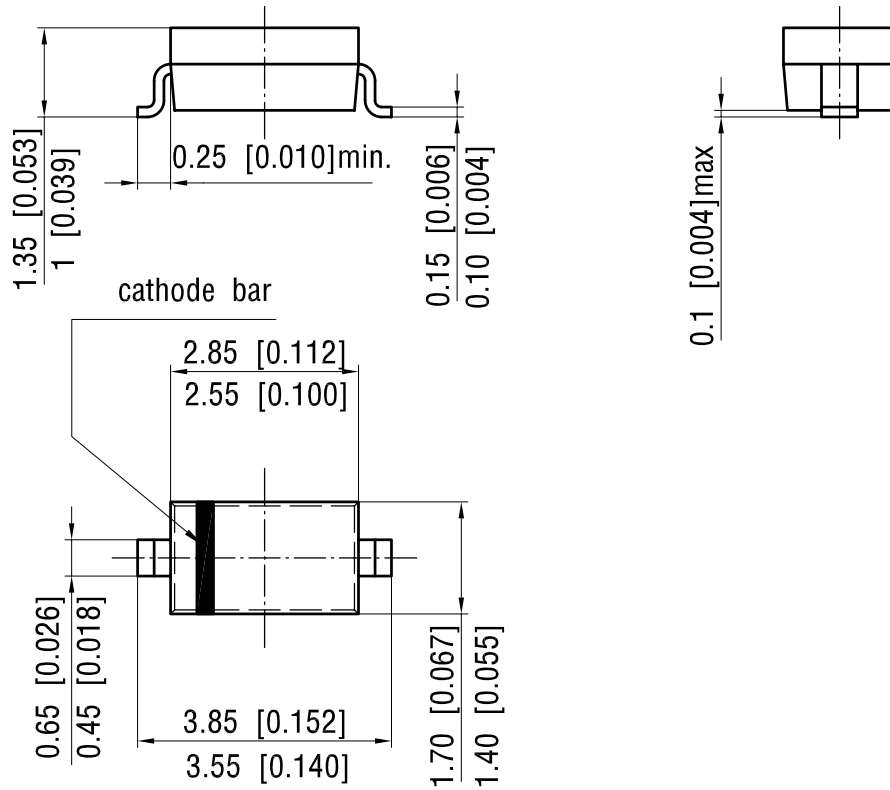
Figure 10. Thermal Response



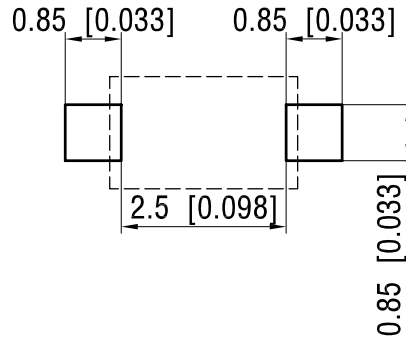
# MMSZ4681-V to MMSZ4717-V

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## Package Dimensions in millimeters (inches): SOD123



foot print recommendation:



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### Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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